

TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA2029FNG, TA2029NG

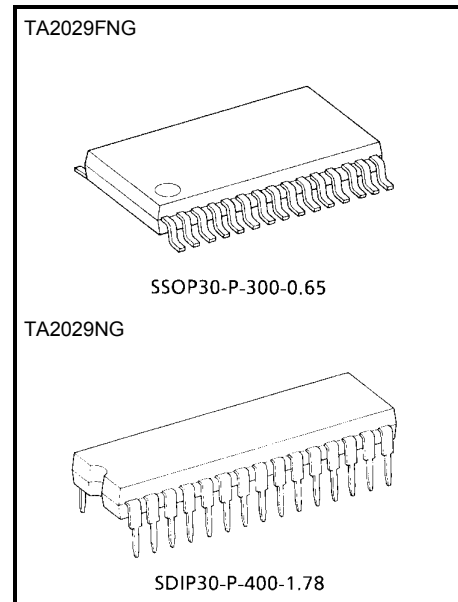
FM F / E + AM / FM IF + PW IC

For Digital Tuning System

The TA2029FNG / NG are AM / FM single chip radio system ICs which are designed for monaural radio. These ICs have many functions and can be used for digital tuning system.

Features

- Built-in FM F / E, AM / FM IF, electronic volume and power amplifier.
- Suitable for combination with digital tuning system which has IF counter.
 - AM / FM IF output for IF counter.
 - FM: 1.3375MHz (1 / 8 IF)
 - AM: 450kHz
 - AM / FM oscillation buffer outputs.
 - Auto stop sensitivity at the searching mode is adjustable by external resistances. (pin (5), pin(6))
- Adjustment-free type FM detector.
- Built-in AF power amplifier, electronic volume and audio muting circuits.
- Detector outputs FM / AM are independent each other.
- $P_o = 100\text{mW}$ (typ.), THD = 10% (FN: 3V / 8 Ω)
 $P_o = 500\text{mW}$ (typ.), THD = 10% (N: 6V / 8 Ω)
- Operating supply voltage range
 : $V_{CC} = 1.8\sim 8\text{V}$ ($T_a = 25^\circ\text{C}$)

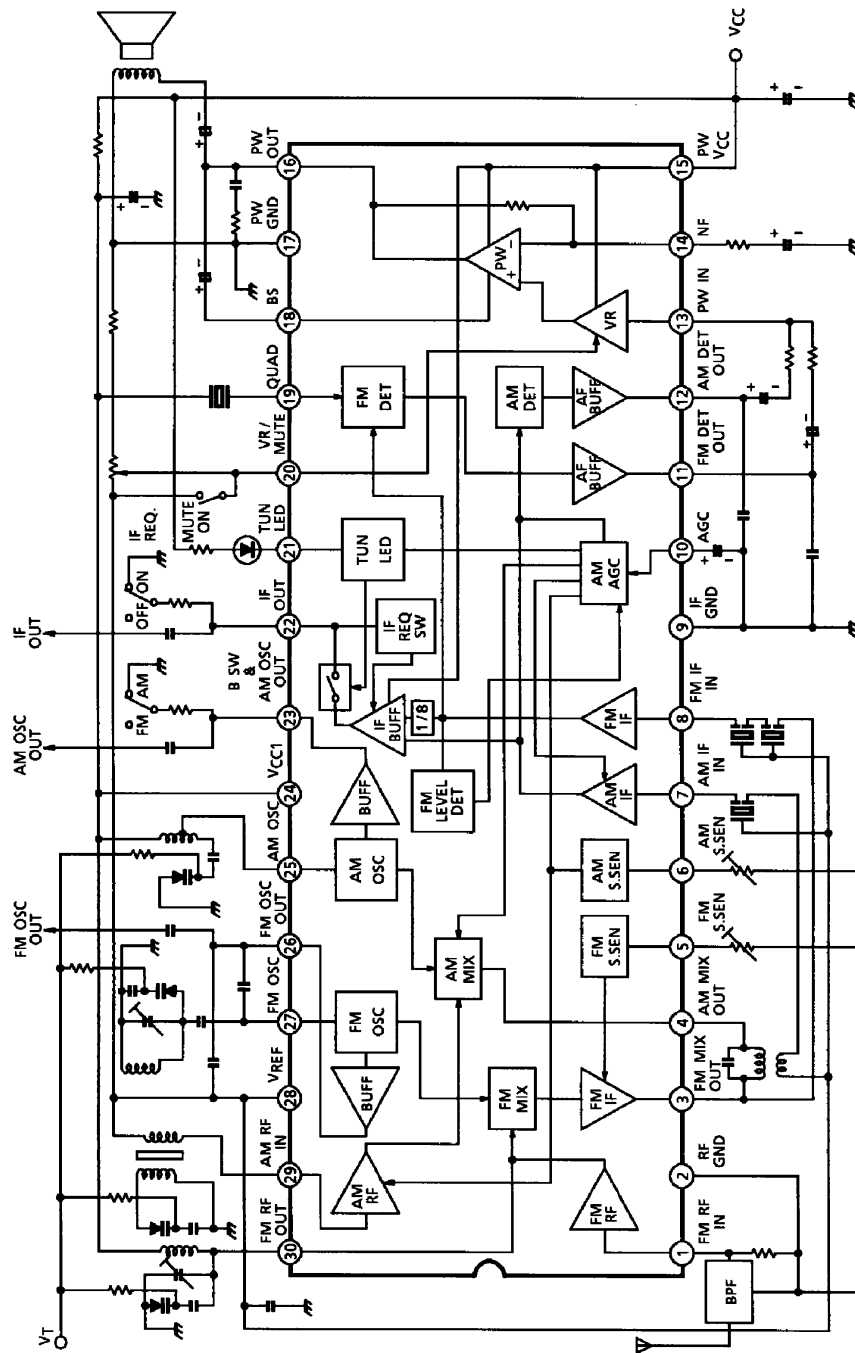


Weight

SSOP30-P-300-0.65: 0.17g (typ.)

SDIP30-P-400-1.78: 2.2g (typ.)

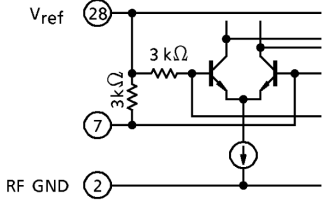
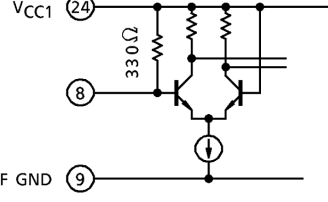
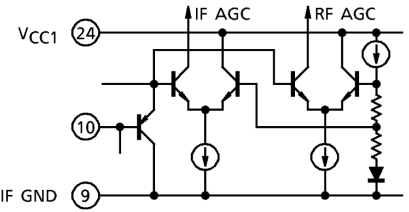
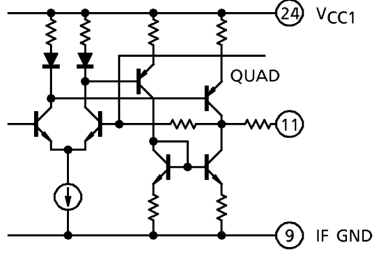
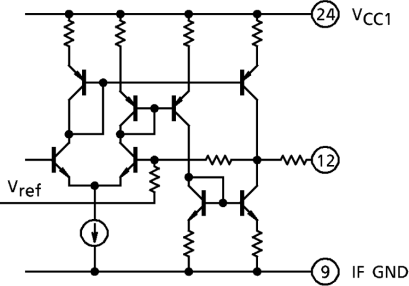
BLOCK DIAGRAM

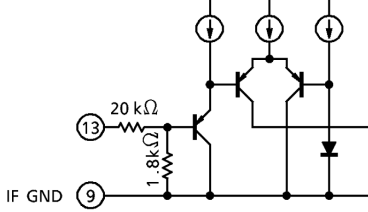
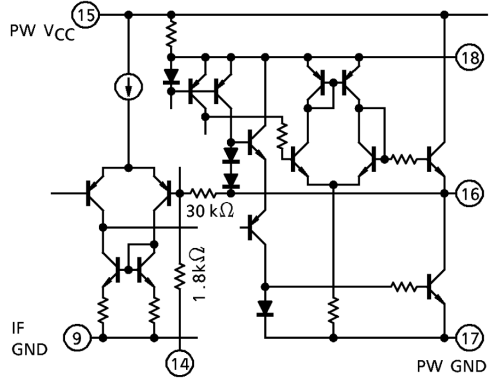
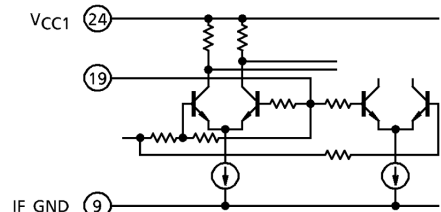
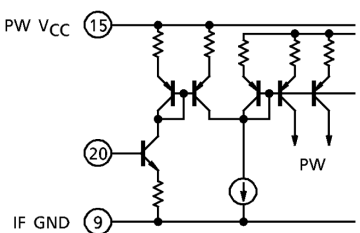
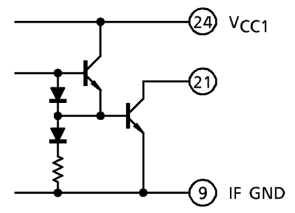


TA2029FNG/NG-2

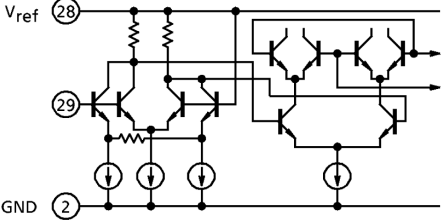
Explanation Of Terminal (Note: $T_a = 25^\circ\text{C}$, $V_{CC} = 3\text{V}$, at no signal)

Pin No.	Characteristic	Internal Circuit	DC Voltage (V) (typ.)	
			AM	FM
1	FM RF in FM RF input terminal		0	0.7
2	RF GND (GND of RF stage)	—	0	0
3	FM mix out Ceramic filter is connected. Recommendation SFE10.7MA5L (murata MFG. Co., LTD)		2.3	1.8
4	AM mix out		2.3	1.8
5	FM S. SEN Adjustable for FM IF output sensitivity by external resistor.		0	0.3
6	AM S. SEN Adjustable for AM IF output sensitivity by external resistor.		0.3	0

Pin No.	Characteristic	Internal Circuit	DC Voltage (V) (typ.)	
			AM	FM
7	AM IF in		1.22	1.2
8	FM IF in		3.0	3.0
9	IF GDN (GDN of AM / FM IF)	—	0	0
10	AGC (AM AGC) Capacitor is connected.		0	0
11	FM DET out FM detector output terminal.		—	1.2
12	AM DET out AM detector output terminal.		0.5	1.2

Pin No.	Characteristic	Internal Circuit	DC Voltage (V) (typ.)	
			AM	FM
13	PW in		0	0
14	NF Capacitor is connected.		0.8	0.8
15	PW V _{CC} (V _{CC} of PW and buffer amplifier for IF counter)		3.0	3.0
16	PW out		1.6	1.6
17	PW GND (GND of PW)		0	0
18	BS Capacitor is connected.		3.0	3.0
19	QUAD FM QUAD detector ceramic discriminator is connected recommendation CDA10.7MG36. (Murat MFG. Co., LTD)		2.5	2.3
20	MUTE / VR • Variable resistor for electronic volume control is connected. • Mute terminal V ₂₀ : V _{ref} → mute on		—	—
21	Tun LED		—	—

Pin No.	Characteristic	Internal Circuit	DC Voltage (V) (typ.)	
			AM	FM
22	IF out IF output terminal pin (22) connects with GND by resistor → come out pin (22): Open → non output		2.5	2.5
23	AM OSC out / band SW AM oscillation buffer output terminal. Bias terminal for AM / FM switch circuit. Pin (23) connects with GND by resistor → AM mode pin (23): Open → FM mode		1.7	2.5
24	VCC1 (VCC of RF stage)	—	3.0	3.0
25	AM OSC AM OSC tank circuit is connected.		3.0	3.0
26	FM OSC out Capacitor is connected between pin (26) and pin (27) shown in the right figure.		0.7	0.5
27	FM OSC FM OSC tank circuit is connected shown in the right figure.		1.22	1.15
28	V _{ref} regulator voltage output terminal V _{ref} = 1.2V (typ.): FM mode 1.22V (typ.): AM mode		1.22	1.2

Pin No.	Characteristic	Internal Circuit	DC Voltage (V) (typ.)	
			AM	FM
29	AM RF in AM RF input terminal.		1.22	1.2
30	FM RF out FM RF tank circuit is connected.	Cf. pin (1)	3.0	3.0

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Supply voltage	V_{CC}	9	V
Power dissipation	TA2029FNG	P_D 500	mW
	TA2029NG	(Note) 1500	
Operating temperature	T_{opr}	-25~75	°C
Storage temperature	T_{stg}	-55~150	°C

(Note): Derated above 25°C in the proportion of 4.8mW / °C for TA2029FNG and 12mW / °C for TA2029NG.

Electrical Characteristics

Unless Otherwise Specified, Ta = 25°C, V_{CC} = 3V, SW₂: Off, SW₃: Off, SW₇ = Off

F / E: f = 83MHz, f_m = 1kHz

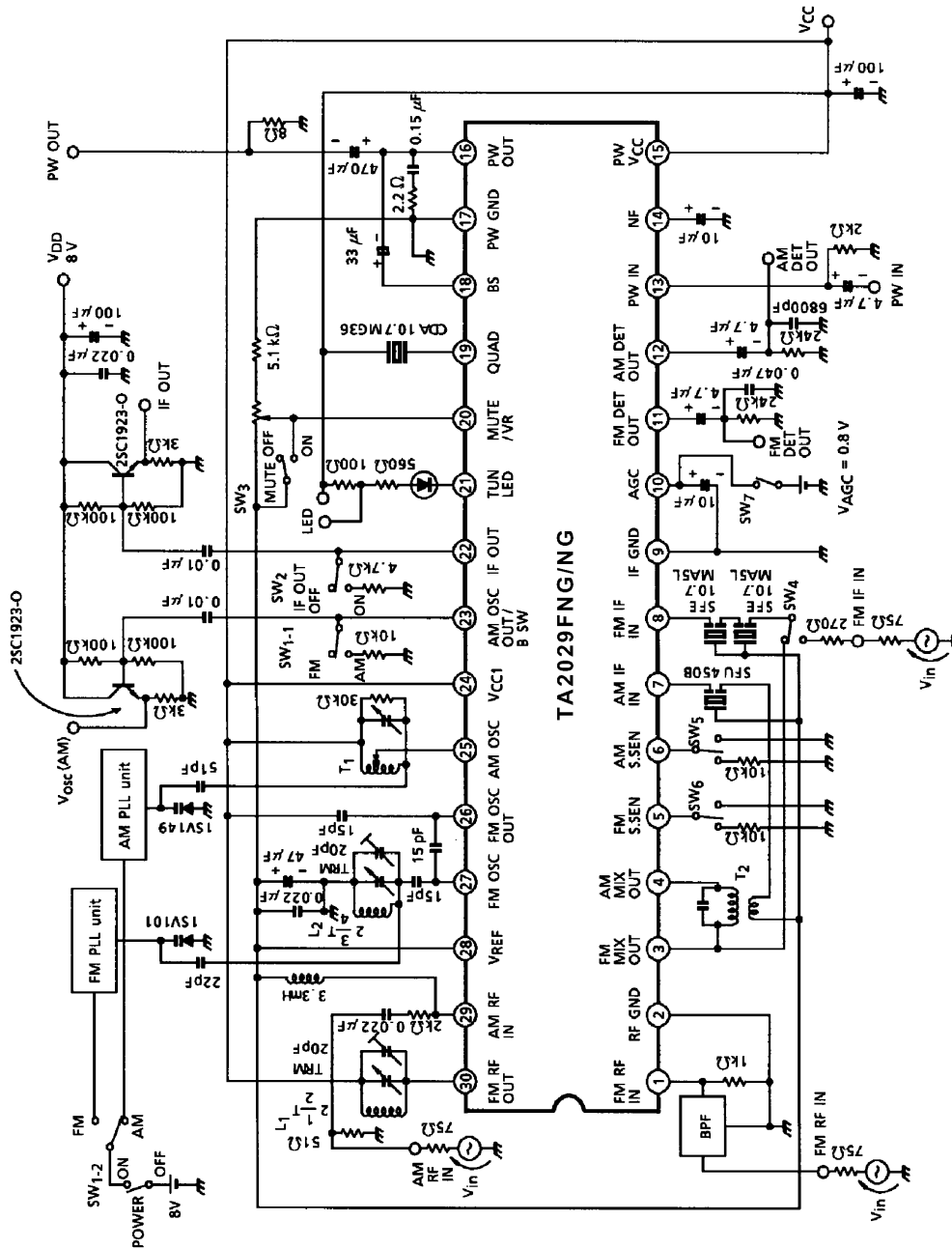
FM IF: f = 10.7MHz, Δf = ±22.5kHz, f_m = 1kHz

AM: f = 1005kHz, MOD = 30%, f_m = 1kHz

Characteristic			Symbol	Test Cir- cuit	Test Condition	Min.	Typ.	Max.	Unit	
Supply current			I _{CCQ} (FM)	1	FM mode V _{in} = 0	Power amp: Off	—	11.5	16.0	mA
			I _{CC} (FM)	1		Power amp: On SW ₂ : On, SW ₇ : On	—	18.0	25.0	
			I _{CCQ} (AM)	1	AM mode	Power amp: Off	—	7.5	11.0	
			I _{CC} (AM)	1	V _{in} = 0	Power amp: On SW ₂ : On, SW ₇ : On	—	17.0	24.0	
F / E	Input limiting voltage		V _{in} (lim)	1	-3dB limiting		—	12	—	dBμV EMF
	Quiescent sensitivity		Q _S		S / N = 30dB		—	15	—	dBμV EMF
	Local OSC stop voltage		V _{stop} (FM)	2	V _{in} = 0		—	1.35	—	V
	Local OSC buffer output voltage		V _{osc} (buff)	2	f _{osc} = 108MHz		—	130	—	mV _{rms}
FM	Input limiting voltage		V _{in} (lim) IF	1	-3dB limiting		39	44	49	dBμV EMF
	Recovered output voltage		V _{OD}	1	V _{in} = 80dBμV EMF		55	80	110	mV _{rms}
	Signal to noise ratio		S / N	1	V _{in} = 80dBμV EMF		—	70	—	dB
	Total harmonic distortion		THD	1	V _{in} = 80dBμV EMF		—	0.4	—	%
	AM rejection ratio		AMR	1	V _{in} = 80dBμV EMF		—	48	—	dB
	LED on sensitivity		V _L	1	I _L = 1mA		40	45	50	dBμV EMF
	IF count output frequency	1 / 8 IF	f1 / 8 IF (FM)	1	SW ₂ : On, V _{in} = 80dBμV EMF		1.3373	1.3375	1.3377	MHz
	IF count output voltage	1 / 8 IF	V1 / 8 IF (FM)	1	SW ₂ : On, V _{in} = 80dBμV EMF		110	200	—	mV _{rms}
	IF count output sensitivity		IF _{sens} (FM)1	1	SW ₆ : 10kΩ		—	48	—	dBμV EMF
			IF _{sens} (FM)2	1	SW ₆ : 0Ω		—	68	—	
	Pin (11) output resistance		R ₁₁	1	—		—	1	—	kΩ

Characteristic		Symbol	Test Cir-cuit	Test Condition	Min.	Typ.	Max.	Unit
AM	Gain	G_V	1	$V_{in} = 26\text{dB}\mu\text{V EMF}$	20	45	80	mV_{rms}
	Recovered output voltage	V_{OD}	1	$V_{in} = 60\text{dB}\mu\text{V EMF}$	50	75	100	mV_{rms}
	Signal to noise ratio	S / N	1	$V_{in} = 60\text{dB}\mu\text{V EMF}$	—	42	—	dB
	Total harmonic distortion	THD	1	$V_{in} = 60\text{dB}\mu\text{V EMF}$	—	1.0	—	%
	LED on sensitivity	V_L	1	$I_L = 1\text{mA}$	24	29	34	$\text{dB}\mu\text{V EMF}$
	Local OSC buff. Output voltage	$V_{osc}(\text{AM})$	1	$f_{osc} = 1455\text{kHz}$	80	140	—	mV_{rms}
	IF count output voltage	$V_{IF}(\text{AM})$	1	SW ₂ : On, $V_{in} = 60\text{dB}\mu\text{V EMF}$	110	200	—	mV_{rms}
	IF count output sensitivity	IFS _{SENS} (AM) 1	1	SW ₅ : 10k Ω	—	29	—	$\text{dB}\mu\text{V EMF}$
		IFS _{SENS} (AM) 2		SW ₅ : 0 Ω	—	45	—	
	Pin (12) output resistance	R_{12}	1	—	—	5	—	k Ω
PW	Voltage gain	G_V	1	$f = 1\text{kHz}$, $R_L = 8\Omega$, $V_o = 0.775V_{\text{rms}}$, SW ₇ : On	27	30	33	dB
	Output power	P_{o1}	1	$f = 1\text{kHz}$, $R_L = 8\Omega$, THD = 10%, SW ₇ : On	70	100	—	mW
		P_{o2}	1	$V_{CC} = 6\text{V}$, $f = 1\text{kHz}$, $R_L = 8\Omega$, THD = 10%, SW ₇ : On	350	500	—	
	Total harmonic distortion	THD	1	$f = 1\text{kHz}$, $R_L = 8\Omega$, $P_o = 50\text{mW}$, SW ₇ : On	—	0.6	1.5	%
	Output noise voltage	V_{no}	1	$R_g = 10\text{k}\Omega$, $R_L = 8\Omega$, SW ₇ : On BPF = 30Hz~20kHz	—	0.45	—	mV_{rms}
	Muting attenuation	ATT	1	$V_o = 0.775V_{\text{rms}}$ SW ₃ : Off $\rightarrow$ on, SW ₇ : On	65	77	—	dB

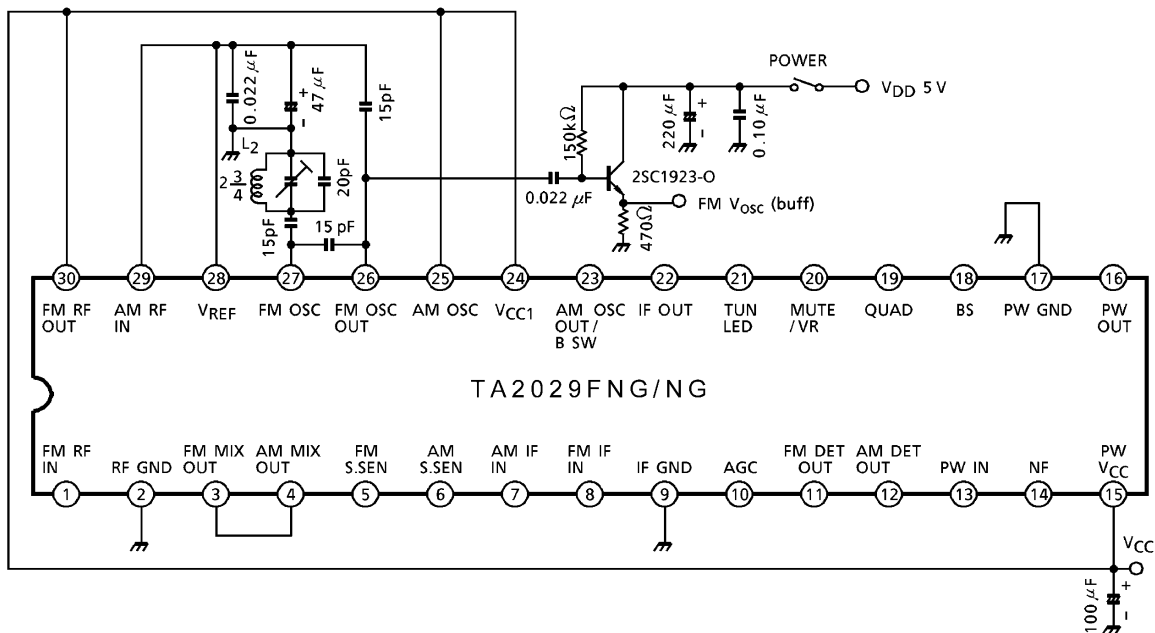
TEST CIRCUIT 1



TA2029FNG/NG

TA2029FNG/NG-10

TEST CIRCUIT 2

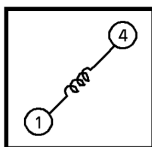


Coil Data

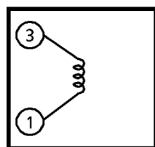
Coil No.	Test Frequency	L (μH)	C ₀ (pF)	Q ₀	Turns					Wire (mmφ)	Ref.
					1-2	2-3	1-3	1-4	4-6		
L ₁ FM RF	100MHz	—	—	100	—	—	—	2 $\frac{1}{2}$	—	0.5 UEW	(S) 53T-037-202
L ₂ FM OSC	100MHz	—	—	100	—	—	2 $\frac{3}{4}$	—	—	0.5 UEW	(S) 0258-244
T ₁ AM OSC	796kHz	288	—	115	13	73	—	—	—	0.08 UEW	(S) 4147-1356-038
T ₂ AM IFT	455kHz	—	180	120	—	—	180	—	15	0.08 UEW	(S) 2150-2162-165

(S) Sumida electric co., LTD

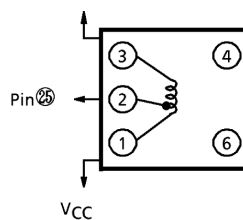
L₁ : FM RF



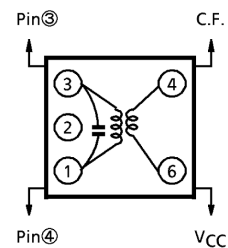
L₂ : FM OSC



T₁ : AM OSC



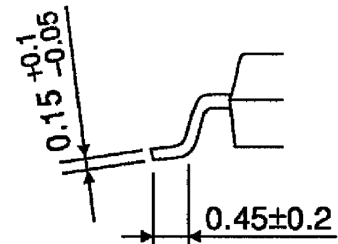
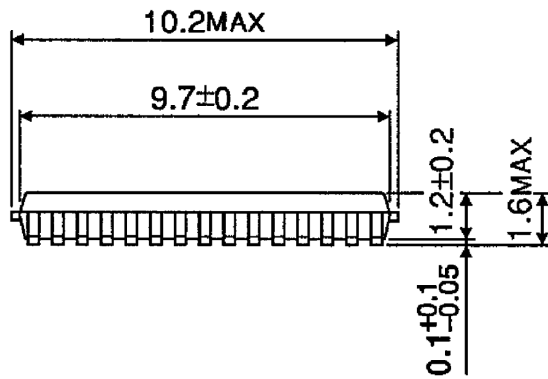
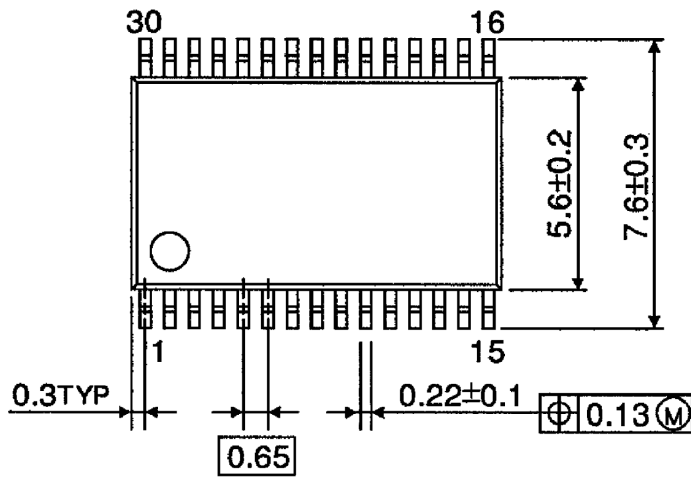
T₂ : AM IFT



PACKAGE DIMENSIONS

SSOP30-P-300-0.65

Unit : mm

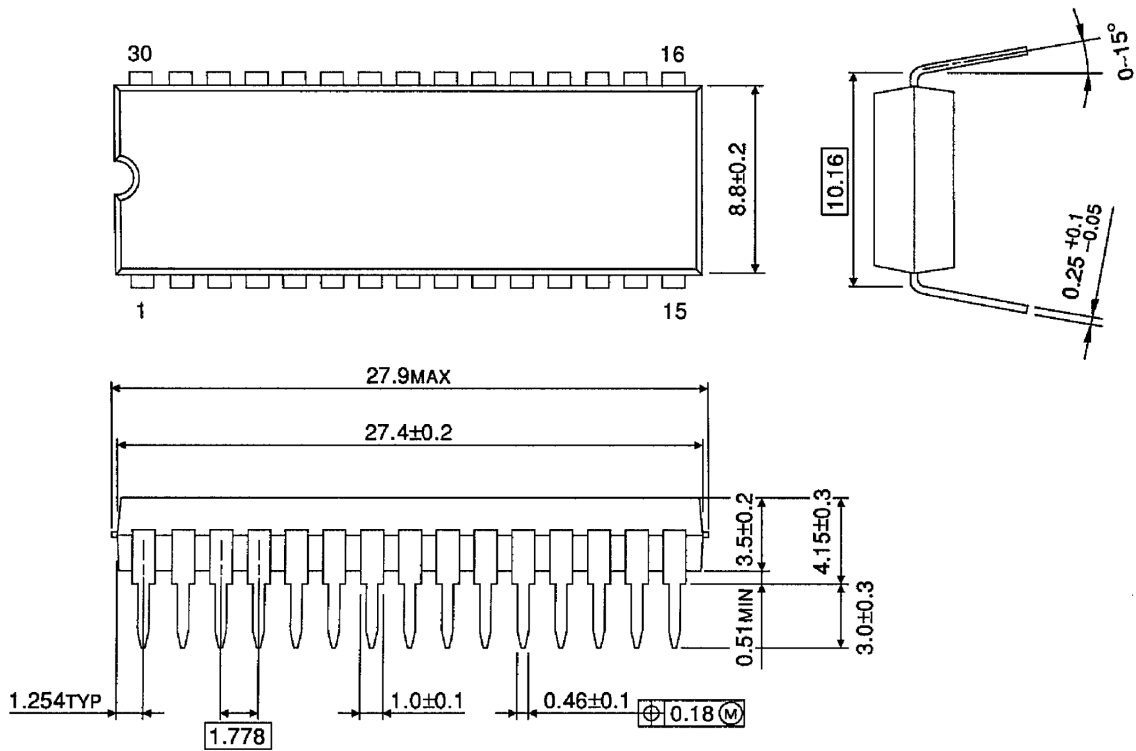


Weight: 0.17g (typ.)

PACKAGE DIMENSIONS

SDIP30-P-400-1.78

Unit : mm



Weight: 2.2g (typ.)

About solderability, following conditions were confirmed

- Solderability

- (1) Use of Sn-63Pb solder Bath

- solder bath temperature = 230°C
 - dipping time = 5 seconds
 - the number of times = once
 - use of R-type flux

- (2) Use of Sn-3.0Ag-0.5Cu solder Bath

- solder bath temperature = 245°C
 - dipping time = 5 seconds
 - the number of times = once
 - use of R-type flux

RESTRICTIONS ON PRODUCT USE

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